Search Hirtory Update 3/18/4 ff.

L Number	Hits	Search Text	DB	Time stamp
1	4859	((29/25.01) or (438/99) or (438/795) or	USPAT;	2004/03/18 15:33
		(438/796) or (438/797) or (438/798) or	US-PGPUB	
		(438/799) or (257/40) or (257/421) or		
		(257/422) or (257/424) or (361/805) or		
		(365/105) or (365/145) or (365/175)).CCLS.	Hanne	0004/03/10 15:30
2	77	1 , , , , , , , , , , , , , , , , , , ,	USPAT;	2004/03/18 15:38
		(438/796) or (438/797) or (438/798) or	US-PGPUB;	
		(438/799) or (257/40) or (257/421) or	EPO; JPO;	
		(257/422) or (257/424) or (361/805) or	DERWENT;	
		(365/105) or (365/145) or	IBM_TDB	
		(365/175)).CCLS.) and (apparatus electric		
		adj field adj (generator modulator)) and		
		(pani polyanaline change adj of adj state		
		(conductive conducting) adj state		
		(semiconducting semiconductive) adj state		
		(non-conducting non-conducting		
		non-conductive non-conductive insulating		
4	1004	insulative) adj state) (apparatus electric adj field adj	USPAT;	2004/03/18 15:40
4	1004	(generator modulator)) and (pani	US-PGPUB;	2004/03/18 13.40
		polyanaline change adj of adj state	EPO; JPO;	
		(conductive conducting) adj state	DERWENT;	
		(semiconducting semiconductive) adj state	IBM TDB	
		(non-conducting nonconducting	1011_100	
		non-conducting non-conducting		
1		insulative) adj state) and (thin adj film		
		tft ofet organic adj thin adj film adj		
		transistor organic adj field adj effect		
		adj transistor)		
5	772	(apparatus electric adj field adj	USPAT;	2004/03/18 15:41
"	''-	(generator modulator)) and (pani	US-PGPUB;	=====================================
		polyanaline change adj of adj state	EPO; JPO;	
		(conductive conducting) adj state	DERWENT;	
		(semiconducting semiconductive) adj state	IBM TDB	
		(non-conducting nonconducting	_	
	1	non-conductive non-conductive insulating		
		insulative) adj state) and (thin adj film		
		tft ofet organic adj thin adj film adj		
		transistor organic adj field adj effect		
		adj transistor) and (matrix matrices		
		three-dimensional "3D" interconnect		
		interconnection array arrays)		
6	45	(apparatus electric adj field adj	USPAT;	2004/03/18 15:41
		(generator modulator)) and (pani	US-PGPUB;	
		polyanaline change adj of adj state	EPO; JPO;	
		(conductive conducting) adj state	DERWENT;	
		(semiconducting semiconductive) adj state	IBM_TDB	
		(non-conducting nonconducting		
		non-conductive non-conductive insulating		1
		insulative) adj state) and (thin adj film		
		tft ofet organic adj thin adj film adj		
		transistor organic adj field adj effect		
		adj transistor) and (matrix matrices		
		three-dimensional "3D" interconnect interconnection array arrays) and		
		(interconnection array arrays) and (interconnect interconnecting		
		interconnect interconnecting interconnection).ti,ab,clm.		
I_ :	1.0	("5043251").PN.) or ("5378916").PN.) or	USPAT;	2004/03/18 15:32
	10	(("5677041").PN.) or (("5537108").PN.) or	US-PGPUB;	2003/03/10 13.32
		(("5808351").PN.) or (("5686341").PN.) or	EPO; JPO;	
1		(("5572409").PN.) or (("5371883").PN.) or	DERWENT;	
		(("5806995").PN.) or (("5825408").PN.)	IBM TDB	
_	2	wo-9509438\$-\$.did.	USPAT;	2002/12/01 16:19
			US-PGPUB;	====, ==, ==, ==
1			EPO; JPO;	
1			DERWENT;	
			IBM TDB	
<u> </u>	L	<u> </u>		·

-	3	978043.ap.	USPAT;	2003/06/27 10:17
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	6	381994.ap.	USPAT;	2003/09/05 13:02
			US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	2	("6461900").PN.	USPAT;	2003/06/27 10:40
	_	, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	1	"4670768".PN.	USPAT	2003/06/27 10:43
_	1		i	
-	1	"5937283".PN.	USPAT	2003/06/27 10:44
_	1	"5696008".PN.	USPAT	2003/06/27 10:44
-	1	"6015725". PN.	USPAT	2003/06/27 10:45
-	1	"5757038". PN.	USPAT	2003/06/27 10:45
-	1	"5723370".PN.	USPAT	2003/06/27 10:46
-	1	"5641694".PN.	USPAT	2003/06/27 10:46
-	1	"5480838".PN.	USPAT	2003/06/27 10:47
_	1	"5308778".PN.	USPAT	2003/06/27 10:47
_	1	"5285093".PN.	USPAT	2003/06/27 10:47
_	2	("5043251").PN.	USPAT;	2003/06/30 11:19
		·	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
l <u>_</u>	2	("5378916").PN.	USPAT;	2003/06/30 11:20
_		(3370910).FN.	US-PGPUB;	2003/00/30 11.20
ł			1	
			EPO; JPO;	
			DERWENT;	
		(NE CERO (4 N)	IBM_TDB	
-	2	("5677041").PN.	USPAT;	2003/06/30 11:20
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1			IBM TDB	
-	2	("5527108").PN.	USPAT;	2003/06/30 11:21
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	ļ .
			IBM TDB	
_	2	("5537108").PN.	USPĀT;	2003/06/30 11:21
]	· · · · · · · · · · · · · · · · · · ·	US-PGPUB;	====, ==, ==
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
I _	2	/"5909351"\ DN		2003/06/30 11-00
I -	4	("5808351").PN.	USPAT;	2003/06/30 11:22
			US-PGPUB;	1
			EPO; JPO;	
1			DERWENT;	
	_		IBM_TDB	
-	2	("5686341").PN.	USPAT;	2003/06/30 11:22
			US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	2	("5572409").PN.	USPAT;	2003/06/30 11:23
			US-PGPUB;	
]		EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	2	("4371883").PN.	USPAT;	2003/06/30 11:23
	-		US-PGPUB;	-000,00,00 11.23
			EPO; JPO;	
1]			
	; I		DERWENT;	
L	11		IBM TDB	<u> </u>

_				
-	2	(("5572409").PN.)	USPAT;	2003/06/30 11:24
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
-	2	("4806995").PN.	USPĀT;	2003/06/30 11:24
			US-PGPUB;	
			EPO; JPO;	i
			DERWENT;	
	}		IBM_TDB	
_	2	("4825408").PN.	USPAT;	2003/06/30 11:25
	}		US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		05004004 4 11 1	IBM_TDB	0000/06/00 11 06
_	2	wo-9509438\$-\$.did.	USPAT;	2003/06/30 11:26
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		03443466 6 444	IBM_TDB	2002/06/20 11:07
-	0	ep-0344346\$-\$.did.	USPAT;	2003/06/30 11:27
			US-PGPUB;	
			EPO; JPO; DERWENT;	
_	2	on-3443469-9 did	<pre>IBM_TDB USPAT;</pre>	2003/06/30 11:28
_	. 4	ep-344346\$-\$.did.		2003/06/30 11:28
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	0	reversible near12 change near12	IBM_TDB USPAT;	2004/03/15 20:48
=		conductivity near12 electric adj field and	US-PGPUB;	2004/03/13 20:48
		(thin adj film thin-film)	EPO; JPO;	
		(thin adj tilm thin-lilm)	DERWENT;	
			IBM TDB	
l <u> </u>	14	change near12 conductivity near12 electric	USPAT;	2003/09/05 11:06
		adj field and (thin adj film thin-film)	US-PGPUB;	2003/03/03 11:00
		adj field and (chin adj film chin film)	EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	10	change near12 conductivity near12 electric	USPAT;	2003/09/05 11:14
		adj field and (438/\$9ccls. 257/\$9.ccls.	US-PGPUB;	
		117/\$9.ccls.)	EPO; JPO;	
1		,	DERWENT;	
	i		IBM TDB	
-	115	pani and thin adj film adj transistor and	USPĀT;	2003/09/05 11:15
	<u> </u>	(array matrix)	US-PGPUB;	
		-	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1		USPĀT;	2003/09/05 11:17
		(array matrix) and electric adj field	US-PGPUB;	
		near6 (conductivity resistivity)	EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
-	68		USPAT;	2003/09/05 13:01
į	1	near12 electric adj field	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	_		IBM_TDB	
_	67	(438/776).CCLS.	USPAT;	2003/09/05 17:33
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		(420 (705), 007.5	IBM_TDB	0000/00/05 35 05
-	558	(438/795).CCLS.	USPAT;	2003/09/05 17:33
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
L		l	IBM_TDB	

	558	(438/795).CCLS.	USPAT;	2003/09/05 17:33
] 338	(436/793).0013.	US-PGPUB;	2003/03/03 17.33
			EPO; JPO;	
			IBM_TDB	0000/00/05 17 00
-	15	(photochemical polyaniline photochemistry)	USPAT;	2003/09/05 17:39
		and ((438/795).CCLS.)	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	29	(438/797).CCLS.	USPĀT;	2003/09/05 17:41
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	302	(438/798).CCLS.	USPĀT;	2003/09/05 17:42
]			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1_	1688	(438/796).CCLS.	IBM_TDB USPAT;	2003/09/05 17:42
	1000	(430/790).0013.	US-PGPUB;	2003/03/03 17.42
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	0000 400 405 45 40
_	2518	((438/796).CCLS.) ((438/798).CCLS.) ((438/797).CCLS.) ((438/795).CCLS.)	USPAT; US-PGPUB;	2003/09/05 17:42
		((436/797).CCLS.) ((436/793).CCLS.)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	41	(((438/796).CCLS.) ((438/798).CCLS.)	USPĀT;	2003/09/05 18:05
		((438/797).CCLS.) ((438/795).CCLS.)) and	US-PGPUB;	
		(electric adj field or (photochemical photochemistry)) and (matrix array)	EPO; JPO; DERWENT;	
		photoenemistry); and (matrix array)	IBM TDB	
_	0	(gmr giant adj magnetic adj resonance)	USPĀT;	2003/09/05 18:07
		near12 electric adj field near12	US-PGPUB;	
		(semiconducting semiconductor insulator	EPO; JPO;	
		insualting) near12 (conductor conductive)	DERWENT; IBM TDB	
_	2	 (gmr giant adj magnetic adj resonance)	USPAT;	2003/09/05 18:07
	_	near12 electric adj field	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	15	"5043251"	IBM_TDB USPAT;	2003/09/12 14:10
	13	0010201	US-PGPUB;	2003,03/12 14.10
			EPO; JPO;	
			DERWENT;	
	1	("50/3251") PN	IBM_TDB	2003/09/12 15:18
-	183	("5043251").PN. apparatus.ti,ab,clm. and (fabricating	USPAT;	2003/09/12 15:18
	100	fabrication) near12 method near12 (thin	US-PGPUB;	-101, 00, 10 10.00
		adj film adj transistor tft otft misfet	EPO; JPO;	
		mosfet mos adj transistor mis adj	DERWENT;	
l _	3	transistor organic adj tft)	IBM_TDB USPAT;	2004/03/15 13:25
-	3	apparatus.ti,ab,clm. and (fabricating fabrication) near12 method near12 (thin	USPAT; US-PGPUB;	2004/03/15 13:25
	 	adj film adj transistor tft otft misfet	EPO; JPO;	
		mosfet mos adj transistor mis adj	DERWENT;	
		transistor organic adj tft) and	IBM_TDB	
_	1564	118/\$9.ccls. ((438/99) or (438/776) or (438/795) or	HCDAT.	2004/03/15 17:08
-	1364	(438/796) or (438/776) or (438/795) or (438/796) or	USPAT; US-PGPUB	2004/03/13 17:08
		(438/799)).CCLS.	33 13135	
-	372	(((438/99) or (438/776) or (438/795) or	USPAT;	2004/03/15 13:52
		(438/796) or (438/797) or (438/798) or	US-PGPUB;	
		(438/799)).CCLS.) and (interconnect	EPO; JPO;	
		interconnection stack stacked)	DERWENT; IBM TDB	
L	l	L	100	L

_	98	(((438/99) or (438/776) or (438/795) or	USPAT;	2004/03/15 15:03
		(438/796) or (438/797) or (438/798) or	US-PGPUB;	
		(438/799)).CCLS.) and (interconnect	EPO; JPO;	
		interconnection stack stacked) and	DERWENT;	
		(ultraviolet ultra-violet uv)	IBM_TDB	
_	24369	apparatus.ti,ab,clm. and semiconductor adj	USPAT;	2004/03/15 14:20
		device.ti,ab,clm.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	25	apparatus.ti,ab,clm. and semiconductor adj	USPAT;	2004/03/15 14:22
		device.ti,ab,clm. and misfet.ti,ab,clm.	US-PGPUB;	
			EPO; JPO;	
		,	DERWENT;	
			IBM_TDB	
_	219	apparatus.ti,ab,clm. and semiconductor adj	USPAT;	2004/03/15 14:23
	•	device.ti,ab,clm. and (mosfet	US-PGPUB;	
		misfet).ti,ab,clm.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	200	apparatus.ti,ab,clm. and semiconductor adj	USPAT;	2004/03/15 14:23
		device.ti,ab,clm. and mosfet.ti,ab,clm.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
-	0	(((438/99) or (438/776) or (438/795) or	USPĀT;	2004/03/15 15:04
		(438/796) or (438/797) or (438/798) or	US-PGPUB;	
		(438/799)).CCLS.) and (interconnect	EPO; JPO;	
		interconnection stack stacked) and	DERWENT;	
		(electric adj field near6 (conductivity	IBM TDB	
		resistivity))	_	
-	6	(US-6458621-\$ or US-6696312-\$ or	USPAT;	2004/03/15 15:22
		US-6635406-\$ or US-6331356-\$ or	US-PGPUB	
		US-5840622-\$).did. or		
	,	(US-20020151117-\$).did.		
-	l o	polymer near2 (integrated adj circuit ic)	USPAT;	2004/03/15 15:23
		near6 electrochemical	US-PGPUB	
-	2	polymer near2 (integrated adj circuit ic)	USPAT;	2004/03/15 15:25
		and electrochemical.ti,ab,clm.	US-PGPUB	
-	1	electrochemical near2	USPAT;	2004/03/15 15:54
		patterning.ti,ab,clm.	US-PGPUB;	
			EPO; JPO;	
ŀ			DERWENT;	
			IBM TDB	
-	2	("5572409").PN.	USPAT;	2004/03/15 15:58
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
-	0	("wo-9944229\$-\$.did.").PN.	USPĀT;	2004/03/15 15:59
]			US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	("wo-99044229\$-\$.did.").PN.	USPĀT;	2004/03/15 15:59
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
-	1	("99044229").PN.	EPO;	2004/03/15 15:59
	1		DERWENT	0004405455
-	3	("9944229").PN.	EPO;	2004/03/15 16:09
[DERWENT	
-	1	("5537108").PN.	USPAT	2004/03/15 16:33
-	0	("apparatusnear6programmablenear6(fuseantif		200PM03/15 16:33
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	

_	54	apparatus near6 programmable near6 (fuse antifuse anti-fuse)	USPAT; US-PGPUB;	2004/03/15 16:34
			EPO; JPO; DERWENT; IBM TDB	
-	44	apparatus near6 programmable near6 (fuse	USPĀT;	2004/03/15 16:38
		antifuse anti-fuse).ti,ab,clm.	US-PGPUB; EPO; JPO;	
			DERWENT; IBM TDB	
-	2676	H01L\$6.ipc. and programmable.ti.	USPĀT;	2004/03/15 16:58
			US-PGPUB; EPO; JPO;	
			DERWENT; IBM TDB	
-	407	H01L\$6.ipc. and programmable.ti. and interconnect\$3.ti,ab,clm.	USPĀT; US-PGPUB;	2004/03/15 16:59
		Interconnects. Li, ab, cim.	EPO; JPO;	
			DERWENT; IBM TDB	
-	191	H01L021\$6.ipc. and programmable.ti. and interconnect\$3.ti,ab,clm.	USPAT; US-PGPUB;	2004/03/15 17:00
		Interconnect of the particular	EPO; JPO;	
			DERWENT; IBM_TDB	
-	0	H01L021/64.ipc. and programmable.ti. and interconnect\$3.ti,ab,clm.	USPAT; US-PGPUB;	2004/03/15 17:00
			EPO; JPO; DERWENT;	
			IBM_TDB	
_	386	H01L021/64.ipc.	USPĀT; US-PGPUB;	2004/03/15 17:13
			EPO; JPO; DERWENT;	
	2	H01L051/80.ipc.	IBM_TDB USPAT;	2004/03/15 17:02
-	2	normosi/ou.ipe.	US-PGPUB;	2004/03/13 17:02
			EPO; JPO; DERWENT;	
_	1	matrix near6 electrode.ti,ab,clm. and	IBM_TDB USPAT;	2004/03/15 17:09
	_	programmable near3 (fuse anti-fuse anti adj fuse antifuse)	US-PGPUB; EPO; JPO;	
		adj luse anciluse)	DERWENT;	
-	2099	(29/25.01).CCLS.	IBM_TDB USPAT;	2004/03/15 17:14
			US-PGPUB; EPO; JPO;	
			DERWENT; IBM TDB	
-	0	(29/25.01and(electrodeelectrodes)near6(arra	/M&PAIxperpe	naacalaby15ccls16
			US-PGPUB; EPO; JPO;	
:			DERWENT; IBM_TDB	
-	30	29/25.01 and (electrode electrodes) near6 (array matrix perpendicular)	USPĀT; US-PGPUB;	2004/03/15 17:16
		,	EPO; JPO; DERWENT;	
		100/05 01 000	IBM_TDB	0004/00/57 55 55
-	456	(29/25.01).CCLS.	USPAT; US-PGPUB	2004/03/15 18:59
_	239	(438/99).CCLS.	USPAT; US-PGPUB	2004/03/15 19:48
-	81	(438/776).CCLS.	USPAT; US-PGPUB	2004/03/15 19:55
-	638	(438/795).CCLS.	USPAT;	2004/03/15 19:55
_	202	(438/796).CCLS.	US-PGPUB USPAT:	2004/03/15 19:55
_	30	(438/797).CCLS.	US-PGPUB USPAT;	2004/03/15 19:55
			US-PGPUB	

	214	(430/300) COLC	USPAT;	2004/03/15 19:55
-	314	(438/798).CCLS.	US-PGPUB	
-	181	(438/799).CCLS.	USPAT; US-PGPUB	2004/03/15 19:55
-	1249	((438/795).CCLS.) ((438/796).CCLS.) ((438/797).CCLS.) ((438/798).CCLS.) ((438/799).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/15 19:55
-	29	(((438/795).CCLS.) ((438/796).CCLS.) ((438/797).CCLS.) ((438/798).CCLS.) ((438/799).CCLS.)) and (electrode electrodes) near12 (electric adj field electric adj fields ultraviolet	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/15 19:57
	59	ultra-violet ultra adj violet uv) (US-6261637-\$ or US-6280585-\$ or US-5858462-\$ or US-6413845-\$ or US-6448492-\$ or US-6140025-\$ or US-5696008-\$ or US-5937283-\$ or US-4670768-\$ or US-6461900-\$ or US-5043251-\$ or US-5371883-\$ or US-5378916-\$ or US-5577108-\$ or US-5572409-\$ or US-5686341-\$ or US-5806995-\$ or US-5686341-\$ or US-5806995-\$ or US-5825408-\$ or US-4825408-\$ or US-4806995-\$ or US-4371883-\$ or US-6429450-\$ or US-6544902-\$ or US-6331356-\$ or US-6544902-\$ or US-6331356-\$ or US-696312-\$ or US-6331356-\$ or US-696312-\$ or US-635406-\$ or US-3829881-\$).did. or (US-20020127833-\$ or US-20020136823-\$ or US-20020153149-\$ or US-20020151117-\$ or US-20020153149-\$ or US-20020151117-\$ or US-20030085439-\$ or US-20020151117-\$ or US-20030119287-\$ or US-20030092267-\$ or US-20030099845-\$).did. or (WO-9509438-\$ or WO-9944229-\$).did. or (US-5858462-\$ or US-5043251-\$ or US-5656548-\$ or EP-159397-\$ or US-5656548-\$ or EP-159397-\$ or	USPAT; US-PGPUB; EPO; DERWENT	2004/03/15 20:20
:		US-4371883-\$ or US-5686341-\$ or US-5537108-\$ or US-5677041-\$ or JP-59191315-\$).did.		
_	2	("6429450").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/15 20:55
-	2	("5686341").PN.	USPĀT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/15 21:00
-	0	w0-9509438\$-\$.did.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/15 21:00
_	2	wo-9509438\$-\$.did.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/15 21:01

_	60	(US-4825408-\$ or US-4806995-\$ or	USPAT;	2004/03/15 21:14
		US-5716218-\$ or US-6544902-\$ or	US-PGPUB;	i
		US-6429450-\$ or US-5808351-\$ or	EPO;	
	1	US-6280585-\$ or US-5858462-\$ or	DERWENT	
		US-3829881-\$ or US-6455359-\$ or		
		US-5840622-\$ or US-6331356-\$ or		ļ .
		US-6458621-\$ or US-6635406-\$ or US-6696312-\$ or US-5686341-\$ or		ŀ
		US-5677041-\$ or US-5806995-\$ or		
		US-6448492-\$ or US-6140025-\$ or		
		US-6413845-\$ or US-6261637-\$ or		
		US-5825408-\$ or US-4371883-\$ or		
		US-4670768-\$ or US-5043251-\$).did. or		
		(US-5371883-\$ or US-5378916-\$ or		!
	1	US-5572409-\$ or US-5537108-\$ or		
		US-5937283-\$ or US-5696008-\$ or		
		US-6461900-\$).did. or (US-20010023771-\$ or		
		US-20040040131-\$ or US-20040009650-\$ or		
		US-20030085439-\$ or US-20020136823-\$ or		
1		US-20030099845-\$ or US-20020057398-\$ or		
		US-20030119287-\$ or US-20030092267-\$ or	1	
	İ	US-20020149107-\$ or US-20020151117-\$ or		
	İ	US-20020127833-\$ or US-20020153149-\$).did.	1	
		or (WO-9944229-\$ or WO-9509438-\$).did. or		
		(US-4806995-\$ or US-5677041-\$ or		
		EP-159397-\$ or US-6432739-\$ or		
		US-5537108-\$ or US-5858462-\$ or		
		JP-59191315-\$ or US-5686341-\$ or		
		US-4371883-\$ or US-5572409-\$ or US-5043251-\$ or US-5656548-\$).did.		
_	1	((US-4825408-\$ or US-4806995-\$ or	USPAT;	2004/03/15 21:15
	1	US-5716218-\$ or US-6544902-\$ or	US-PGPUB;	2004/03/13 21:13
ŀ		US-6429450-\$ or US-5808351-\$ or	EPO; JPO;	
		US-6280585-\$ or US-5858462-\$ or	DERWENT;	
		US-3829881-\$ or US-6455359-\$ or	IBM TDB	
		US-5840622-\$ or US-6331356-\$ or	_	
		US-6458621-\$ or US-6635406-\$ or		
		US-6696312-\$ or US-5686341-\$ or		
		US-5677041-\$ or US-5806995-\$ or		
		US-6448492-\$ or US-6140025-\$ or		1
		US-6413845-\$ or US-6261637-\$ or]
		US-5825408-\$ or US-4371883-\$ or		1
		US-4670768-\$ or US-5043251-\$).did. or		
		(US-5371883-\$ or US-5378916-\$ or		
		US-5572409-\$ or US-5537108-\$ or US-5937283-\$ or US-5696008-\$ or		
		US-6461900-\$).did. or (US-20010023771-\$ or		
		US-20040040131-\$ or US-20040009650-\$ or		
		US-20030085439-\$ or US-20020136823-\$ or		
		US-20030099845-\$ or US-20020057398-\$ or	1	ļ
		US-20030119287-\$ or US-20030092267-\$ or	1	
		US-20020149107-\$ or US-20020151117-\$ or	•	
		US-20020127833-\$ or US-20020153149-\$).did.		
	-	or (WO-9944229-\$ or WO-9509438-\$).did. or		
		(US-4806995-\$ or US-5677041-\$ or		
		EP-159397-\$ or US-6432739-\$ or		
		US-5537108-\$ or US-5858462-\$ or		
	1	JP-59191315-\$ or US-5686341-\$ or	1.	
		US-4371883-\$ or US-5572409-\$ or	1	
		US-5043251-\$ or US-5656548-\$).did.) and sonnenschein.in.		
1_	4085	sonnenschein.in. ((257/421) or (257/421) or (257/758) or	USPAT;	2004/03/15 21:18
	1003	((257/421) of (257/421) of (257/736) of (257/776) or (257/6) or (257/432) or	US-PGPUB	2004/03/13 21:18
		(257/739) or (438/130) or (361/805)).CCLS.	05 13105	
-	332	(((257/421) or (257/421) or (257/758) or	USPAT;	2004/03/15 21:19
]	(257/776) or (257/6) or (257/432) or	US-PGPUB;	=====
1	1	(257/739) or (438/130) or	EPO; JPO;	
1	1	(361/805)).CCLS.) and (pani polyaniline uv	DERWENT;	
		ultraviolet ultra-violet ultra adj violet)	IBM TDB	1

-	25	(((257/421) or (257/421) or (257/758) or	USPAT;	2004/03/15 21:20
		(257/776) or (257/6) or (257/432) or	US-PGPUB;	
		(257/739) or (438/130) or	EPO; JPO;	
		(361/805)).CCLS.) and (pani polyaniline uv ultraviolet ultra-violet ultra adj violet	DERWENT; IBM_TDB	
		electric adj field) and (conductive	I IDM_IDD	
		conduction) near2 (state resistive)		
_	56		USPAT;	2004/03/15 21:28
		(257/776) or (257/6) or (257/432) or	US-PGPUB;	2001,00,20 ==121
		(257/739) or (438/130) or	EPO; JPO;	
		(361/805)).CCLS.) and (pani polyaniline uv	DERWENT;	
		ultraviolet ultra-violet ultra adj violet	IBM_TDB	
1		electric adj field) and (conductive		
		conduction) near12 (state resistive)		0004/00/15 01 00
-	1106	(257/40).CCLS.	USPAT;	2004/03/15 21:28
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	457	((257/40).CCLS.) and (apparatus	USPAT;	2004/03/15 21:29
	10,	method).ti,ab,clm.	US-PGPUB;	2001,00,10 01115
			EPO; JPO;	
	İ		DERWENT;	
			IBM_TDB	
-	394	(((257/40).CCLS.) and (apparatus	USPĀT;	2004/03/15 21:29
		method).ti,ab,clm.) not (((438/99) or	US-PGPUB;	
		(438/776) or (438/795) or (438/796) or	EPO; JPO;	
		(438/797) or (438/798) or	DERWENT;	
	261	(438/799)).CCLS.)	IBM_TDB	2004/03/16 16:05
-	361	((257/421) or (257/424)).CCLS.	USPAT; US-PGPUB	2004/03/16 16:03
_	6	(((257/421) or (257/424)).CCLS.) and	USPAT;	2004/03/16 15:41
	0	(array matrix matrices) near6 (electrode	US-PGPUB;	2004/03/10 13:41
		electrodes)	EPO; JPO;	
		5255224557	DERWENT;	
			IBM TDB	
_	153	(257/422).CCLS.	USPAT;	2004/03/16 16:05
			US-PGPUB	
-	64	(US-5371883-\$ or US-5043251-\$ or	USPAT;	2004/03/16 16:15
		US-5378916-\$ or US-5537108-\$ or	US-PGPUB;	
		US-5572409-\$ or US-5677041-\$ or	EPO;	
		US-5806995-\$ or US-5686341-\$ or US-6331356-\$ or US-6429450-\$ or	DERWENT	
		US-6458621-\$ or US-6635406-\$ or		1
		US-6696312-\$ or US-5808351-\$ or		
		US-5825408-\$ or US-3340463-\$ or		
		US-3593045-\$ or US-4667391-\$ or		
		US-5179429-\$ or US-5858462-\$ or		
		US-6140025-\$ or US-6261637-\$ or		
		US-6280585-\$ or US-6413845-\$ or		
		US-6448492-\$ or US-5840622-\$).did. or		
		(US-3829881-\$ or US-4825408-\$ or		
		US-6544902-\$ or US-5716218-\$ or		
		US-4371883-\$ or US-6455359-\$ or US-5937283-\$ or US-4670768-\$ or		
		US-5937283-\$ or US-4670768-\$ or US-5696008-\$ or US-6461900-\$ or		
]		US-4806995-\$).did. or (US-20030085439-\$ or		
		US-20020151117-\$ or US-20020127833-\$ or		
		US-20010023771-\$ or US-20020153149-\$ or		
		US-20040009650-\$ or US-20040040131-\$ or		
		US-20030099845-\$ or US-20020057398-\$ or		
		US-20020136823-\$ or US-20020149107-\$ or		
		US-20030092267-\$ or US-20030119287-\$).did.		
		or (WO-9944229-\$ or WO-9509438-\$).did. or		
]		(US-5656548-\$ or US-6432739-\$ or		
		JP-59191315-\$ or US-5858462-\$ or		
]		EP-159397-\$ or US-4806995-\$ or		
		US-4371883-\$ or US-5572409-\$ or US-5686341-\$ or US-5537108-\$ or		
		US-5677041-\$ or US-5043251-\$).did.		
L	L	OO OO!!OTT 4 OT OO-OUTOZOT-4/.UIU.	L	L

				·
-	160	parallel adj (strips electrodes) and	USPAT;	2004/03/16 16:29
		365/\$9.ccls.	US-PGPUB; EPO; JPO;	1
			1	
			DERWENT; IBM TDB	
_	29	 parallel adj (strips electrodes) near6	USPAT;	2004/03/16 16:30
-	23	(perpendicularly perpendicular orthogonal	US-PGPUB;	2004/05/10 10:50
		orthogonally) and 365/\$9.ccls.	EPO; JPO;	
		l orenogonarry, and 303,43.0013.	DERWENT;	
			IBM TDB	
_	4	(US-6498744-\$ or US-6670659-\$ or	USPĀT	2004/03/16 16:43
		US-6055180-\$ or US-6236587-\$).did.		
-	163	(365/105).CCLS.	USPAT;	2004/03/16 16:43
			US-PGPUB	
-	1151	(365/145).CCLS.	USPAT;	2004/03/16 16:43
			US-PGPUB	
-	320	(365/175).CCLS.	USPAT;	2004/03/16 16:43
			US-PGPUB	
-	1579	((365/105).CCLS.) ((365/145).CCLS.)	USPAT;	2004/03/16 16:44
		((365/175).CCLS.)	US-PGPUB;	ł
			EPO; JPO;	
			DERWENT; IBM TDB	
	16	(((365/105).CCLS.) ((365/145).CCLS.)	USPAT;	2004/03/16 18:36
	16	((365/175).CCLS.)) and parallel near6	US-PGPUB;	2004/03/10 10.30
		(electrodes strips plates) near12	EPO; JPO;	
		(orthogonal orthogonally perpedicular	DERWENT;	
		perpendicularly)	IBM TDB	
-	0	parallel near6 (electrodes strips plates)	USPAT;	2004/03/16 18:40
		near12 (orthogonal orthogonally	US-PGPUB;	·
		perpedicular perpendicularly) and	EPO; JPO;	
		(polyaniline pani) and (ultraviolet	DERWENT;	
		ultra-violet ultra adj violet)	IBM_TDB	
-	17	parallel near6 (electrodes strips plates)	USPAT;	2004/03/16 18:41
		near12 (orthogonal orthogonally	US-PGPUB;	
		perpedicular perpendicularly) and	EPO; JPO;	
		(polyaniline pani)	DERWENT; IBM TDB	
_	2	("3586415").PN.	USPAT;	2004/03/17 13:42
		(3300413).114.	US-PGPUB;	2004/03/17 13.42
			EPO; JPO;	
			DERWENT;	
]			IBM TDB	
-	2	("5667041").PN.	USPAT;	2004/03/17 13:43
			US-PGPUB;	,
			EPO; JPO;	
<u> </u>			DERWENT;	
[IBM_TDB	
-	2	("5677041").PN.	USPAT;	2004/03/17 13:43
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	5	012023.ap.	IBM_TDB USPAT;	2004/03/17 17:02
	3	υτευευ.αμ.	US-PGPUB;	2004/03/11 11:02
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	2	("5742074").PN.	USPAT;	2004/03/17 17:21
			US-PGPUB;	
[EPO; JPO;	
	İ		DERWENT;	
			IBM_TDB	
-	1063	(257/48).CCLS.	USPAT;	2004/03/17 17:22
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
			אמד הומדו	

[-	22	((257/48).CCLS.) and (bus bus-line bus adj	USPAT;	2004/03/17 17:23
		line) and display and (monitor monitoring test testing)	US-PGPUB; EPO; JPO; DERWENT; IBM TDB	
-	23	((257/48).CCLS.) and (bus bus-line bus adj line) and display and (inspect inspecting monitor monitoring test testing)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/17 17:23